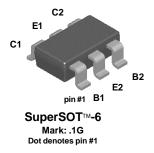


FMBA06



NPN Multi-Chip General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 33.

Absolute Maximum Ratings* T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{CEO}	Collector-Emitter Voltage	80	V	
V _{CBO}	Collector-Base Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	4.0	V	
I _C	Collector Current - Continuous	500	mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics T_A = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		FMBA06	
P _D	Total Device Dissipation	700	mW
	Derate above 25°C	5.6	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	180	°C/W

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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NPN Multi-Chip General Purpose Amplifier

(continued)

Electrical Characteristics

 $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
OFF CHAF	RACTERISTICS					

V _{(BR)CEO}	Collector-Emitter Sustaining Voltage*	$I_C = 1.0 \text{ mA}, I_B = 0$	80		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	4.0		V
I _{CEO}	Collector-Cutoff Current	V _{CE} = 60 V, I _B = 0		0.1	μΑ
I _{CBO}	Collector-Cutoff Current	V _{CB} = 80 V, I _E = 0		0.1	μΑ

ON CHARACTERISTICS

h _{FE}	DC Current Gain	$I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_C = 100 \text{ mA}, V_{CE} = 1.0 \text{ V}$	100 100		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$		0.25	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 100 mA, V _{CE} = 1.0 V		1.2	V

SMALL SIGNAL CHARACTERISTICS

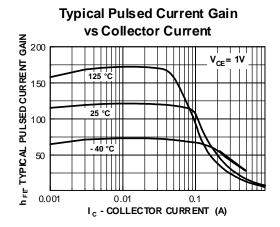
f_{T}	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 2.0 \text{ V},$	100	MHz
		f = 100 MHz		

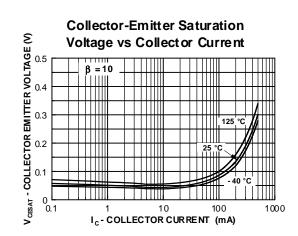
^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

Spice Model

NPN (Is=8.324f Xti=3 Eg=1.11 Vaf=100 Bf=12.16K Ne=1.368 Ise=73.27f Ikf=.1096 Xtb=1.5 Br=11.1 Nc=2 Isc=0 Ikr=0 Rc=.25 Cjc=18.36p Mjc=.3843 Vjc=.75 Fc=.5 Cje=55.61p Mje=.3834 Vje=.75 Tr=72.15n Tf=516.1p Itf=.5 Vtf=4 Xtf=6 Rb=10)

Typical Characteristics

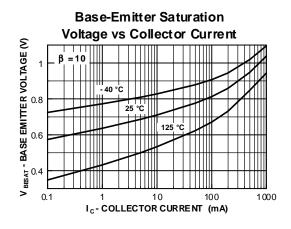


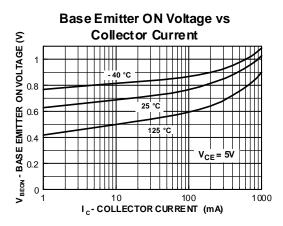


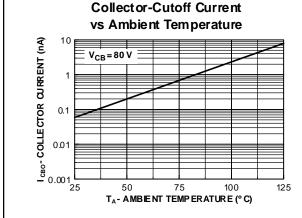
NPN Multi-Chip General Purpose Amplifier

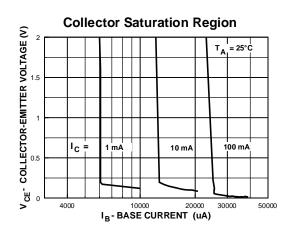
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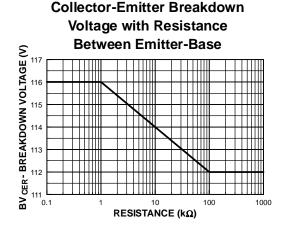
Typical Characteristics (continued)

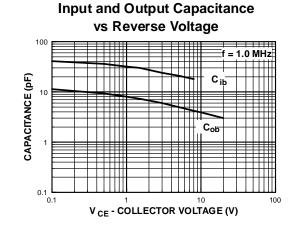








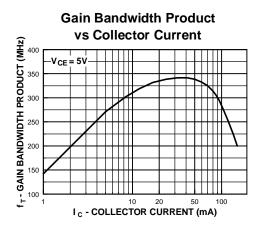


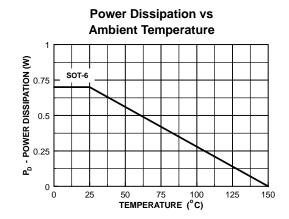


NPN Multi-Chip General Purpose Amplifier

(continued)

Typical Characteristics (continued)





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Definition of Terms

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Rev. G